

# DATA SHEET



## **PDTA114ES** PNP resistor-equipped transistor

Product specification  
Supersedes data of 1997 Jul 02  
File under Discrete Semiconductors, SC04

1998 May 18

# PNP resistor-equipped transistor

# PDTA114ES

### FEATURES

- Built-in bias resistors  
R1 and R2 (typ. 10 kΩ each)
- Simplification of circuit design
- Reduces number of components and board space.

### APPLICATIONS

- Especially suitable for space reduction in interface and driver circuit applications
- Inverter circuit configurations without use of external resistors.

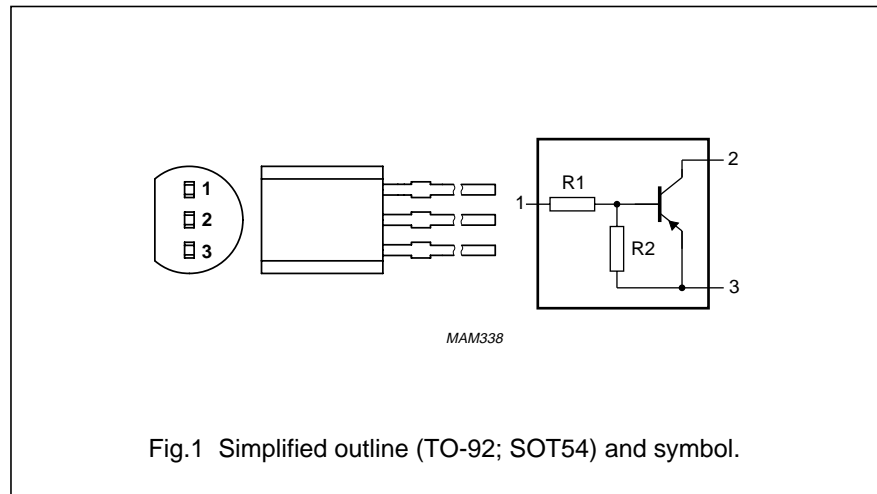


Fig.1 Simplified outline (TO-92; SOT54) and symbol.

### DESCRIPTION

PNP resistor-equipped transistor in a TO-92; SOT54 plastic package.  
NPN complement: PDTA114ES.

### PINNING

PIN	DESCRIPTION
1	base/input
2	collector/output
3	emitter/ground (+)

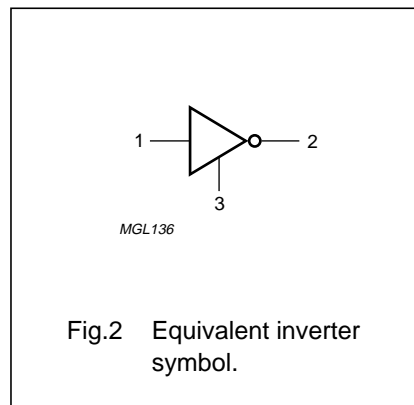


Fig.2 Equivalent inverter symbol.

### QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{CE0}$	collector-emitter voltage	open base	–	–	–50	V
$I_O$	output current (DC)		–	–	–100	mA
$I_{CM}$	peak collector current		–	–	–100	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ }^\circ\text{C}$	–	–	500	mW
$h_{FE}$	DC current gain	$I_C = -5\text{ mA}; V_{CE} = -5\text{ V}$	30	–	–	
R1	input resistor		7	10	13	kΩ
$\frac{R2}{R1}$	resistor ratio		0.8	1	1.2	

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**LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	–50	V
$V_{CEO}$	collector-emitter voltage	open base	–	–50	V
$V_{EBO}$	emitter-base voltage	open collector	–	–10	V
$V_i$	input voltage				
	positive		–	+10	V
	negative		–	–40	V
$I_O$	output current (DC)		–	–100	mA
$I_{CM}$	peak collector current		–	–100	mA
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ °C}$ ; note 1	–	500	mW
$T_{stg}$	storage temperature		–65	+150	°C
$T_j$	junction temperature		–	150	°C
$T_{amb}$	operating ambient temperature		–65	+150	°C

**Note**

1. Transistor mounted on an FR4 printed-circuit board.

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE.	UNIT
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	250	K/W

**Note**

1. Transistor mounted on an FR4 printed-circuit board.

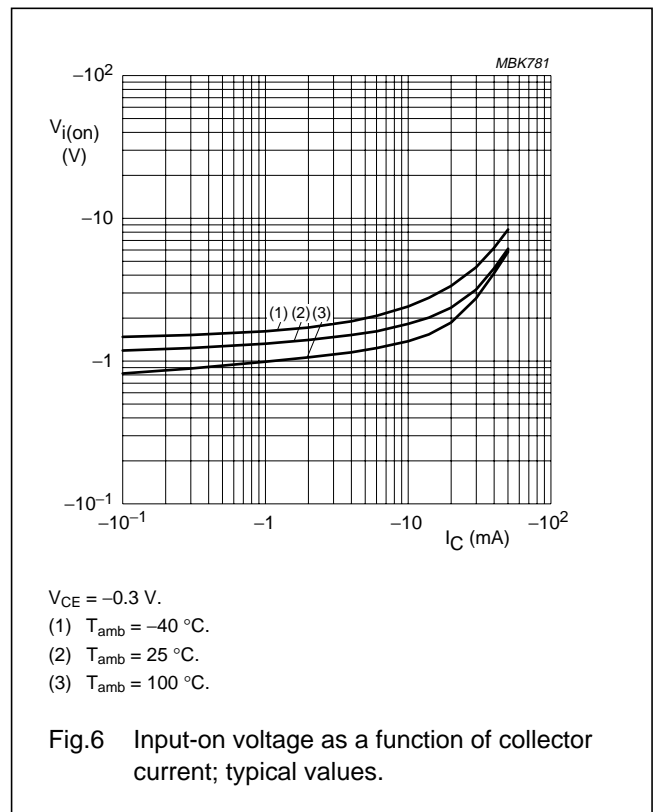
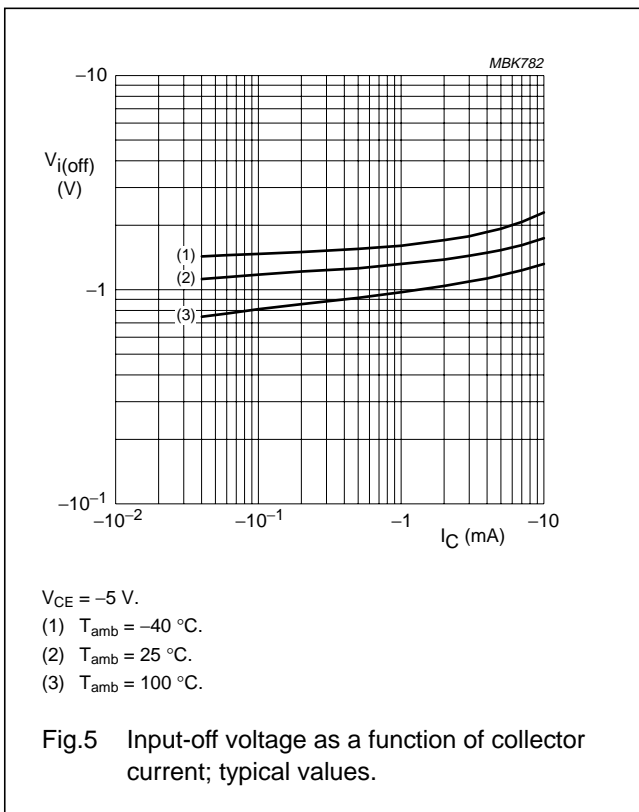
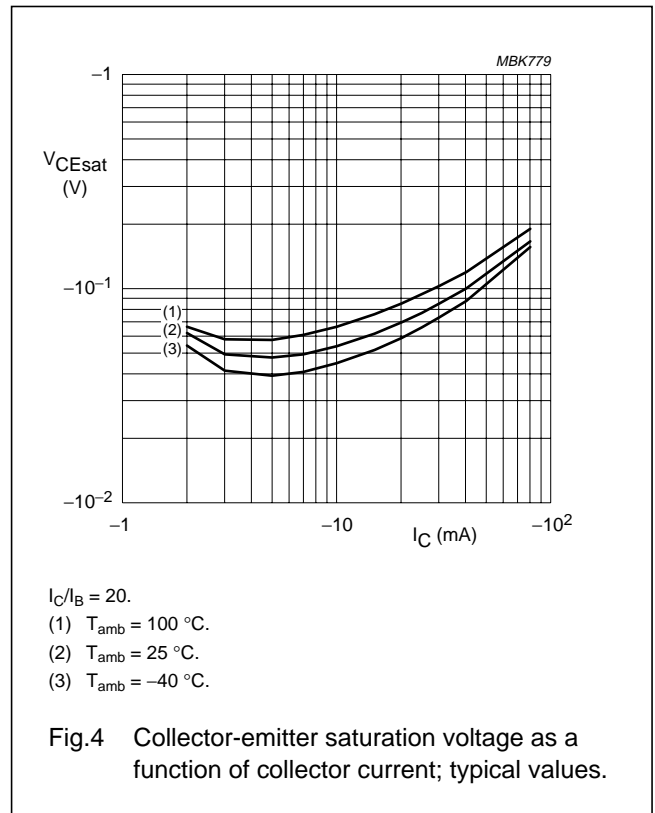
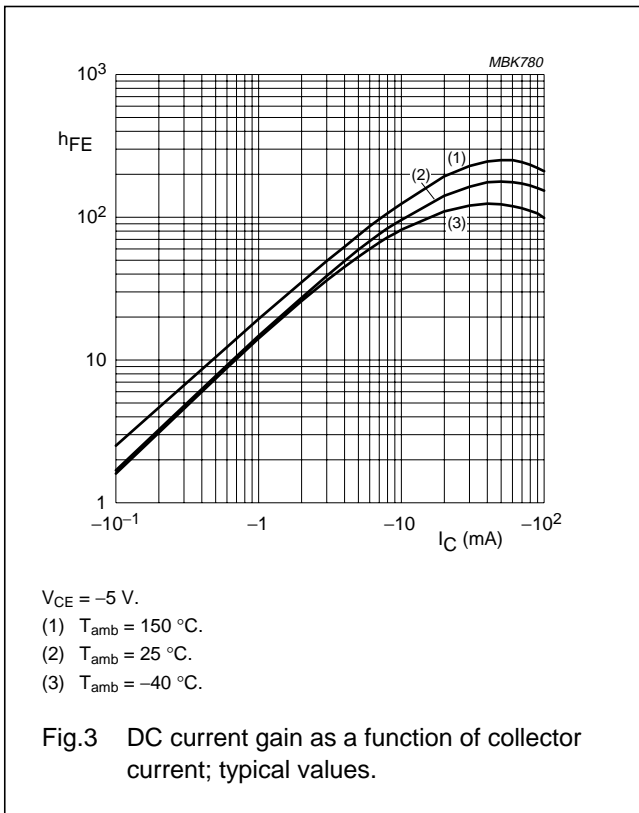
**CHARACTERISTICS**

$T_{amb} = 25\text{ °C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$I_{CBO}$	collector cut-off current	$I_E = 0$ ; $V_{CB} = -50\text{ V}$	–	–	–100	nA
$I_{CEO}$	collector cut-off current	$I_B = 0$ ; $V_{CE} = -30\text{ V}$	–	–	–1	$\mu\text{A}$
		$I_B = 0$ ; $V_{CE} = -30\text{ V}$ ; $T_j = 150\text{ °C}$	–	–	–50	$\mu\text{A}$
$I_{EBO}$	emitter cut-off current	$I_C = 0$ ; $V_{EB} = -5\text{ V}$	–	–	–400	$\mu\text{A}$
$h_{FE}$	DC current gain	$I_C = -5\text{ mA}$ ; $V_{CE} = -5\text{ V}$	30	–	–	
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = -10\text{ mA}$ ; $I_B = -0.5\text{ mA}$	–	–	–150	mV
$V_{i(off)}$	input-off voltage	$I_C = -100\text{ }\mu\text{A}$ ; $V_{CE} = -5\text{ V}$	–	–1.1	–0.8	V
$V_{i(on)}$	input-on voltage	$I_C = -10\text{ mA}$ ; $V_{CE} = -0.3\text{ V}$	–2.5	–1.8	–	V
R1	input resistor		7	10	13	k $\Omega$
$\frac{R2}{R1}$	resistor ratio		0.8	1	1.2	
$C_c$	collector capacitance	$I_E = I_e = 0$ ; $V_{CB} = -10\text{ V}$ ; $f = 1\text{ MHz}$	–	–	3	pF

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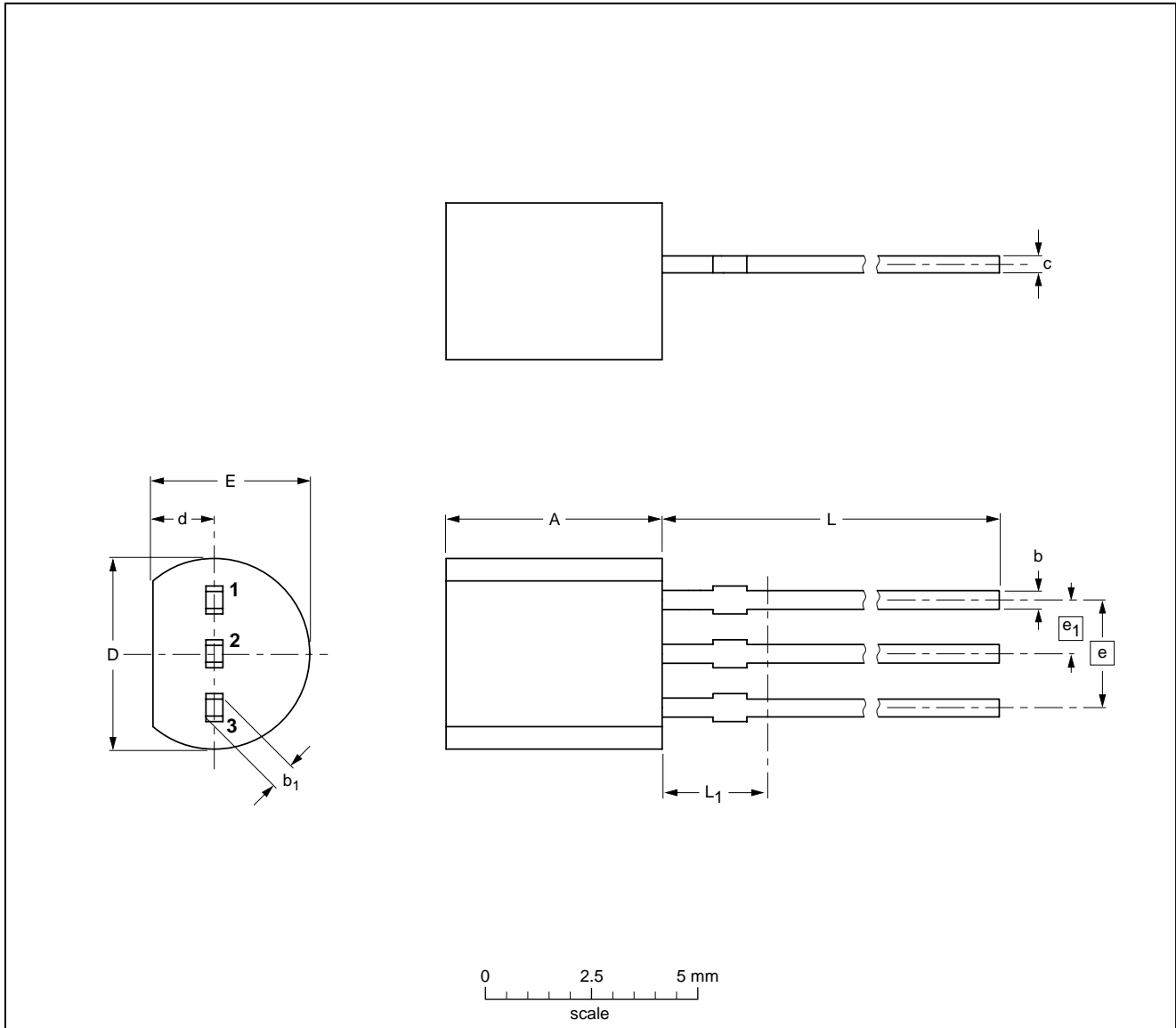
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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

UNIT	A	b	b <sub>1</sub>	c	D	d	E	e	e <sub>1</sub>	L	L <sub>1</sub> <sup>(1)</sup>
mm	5.2 5.0	0.48 0.40	0.66 0.56	0.45 0.40	4.8 4.4	1.7 1.4	4.2 3.6	2.54	1.27	14.5 12.7	2.5

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ		
SOT54		TO-92	SC-43		97-02-28

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**DEFINITIONS**

<b>Data sheet status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

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